NSN 5961-01-069-5023

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View Online at https://aerobasegroup.com/nsn/5961-01-069-5023 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 50.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 92059-900322 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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